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Discontinued

Preliminary



SANYO Semiconductors

DATA SHEET

STK760-220A-E — Single-phase Rectification

Thick-Film Hybrid IC PFC Hybrid IC

Overview

The STK760-220A-E is an average current control type hybrid IC that integrates in a single package the power stages for the step-up active converter and the control IC, and overcurrent/overvoltage protection circuits. It is designed to improve the power factor of single-phase AC power supplies.

Applications

• Power rectification for air conditioners and general-purpose inverters as a single-phase rectification active converter.

Features

- IGBT switching power device employed in the active converter output stage.
- On-chip regulator for PFC control supports a wide range of input voltage (up to 50V).
- Full complement of protection circuits, including overcurrent, overvoltage, and undervoltage protection, plus soft start function.
- Logic level PFC controlled ON/OFF control.
- On-chip light-load correction circuit that minimizes output voltage increase when no load is applied.
- SIP package providing a high degree freedom for mounting the IC in the set.

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Specifications

Absolute maximum ratings at $Tc = 25^{\circ}C$

	Paramete	er	Symbol	Conditions	Ratings	unit
IGBT	Collector-to-e	emitter voltage	VCES		600	V
(TR2+TR3)	Repetitive pe	Repetitive peak collector current		*1	180	Α
	Collector current		ΙC		70	Α
	Allowable power dissipation		Pd		166	W
FRD	Diode reverse	Diode reverse voltage			600	V
(D2)	Repetitive pe	ak forward current	IF2P	*1	160	Α
	Forward Curr	rent	IF2		41	Α
	Allowable por	wer dissipation	Pd		73	W
FRD	Repetitive pe	ak forward current	IFP	*1	15	Α
(D3)	Forward curre	ent	IF3		7	Α
	Allowable por	wer dissipation	Pd		13	W
Supply voltage	(Pin 1)		Vs		21 to 50	V
Supply current	(Pin 1)		lsc		60	mA
Signal pin input voltage Pin 5			VVDET			
Pin 12 Pin 13 Pin 9		VEI		-0.3 to 5.0	v	
		VOVP				
		VIS		-10 to 5.0	V	
		Pin 4	VONF		-0.3 to V _{CC}	V
Oscillation freq	uency	·	fosc		40	kHz
Maximum AC ir	nput voltage		VAC	Single-phase full-wave rectification waveform voltage	264	v
Maximum outpi	ut voltage		VO	Under the operating conditions of the application circuit	450	v
Input current (in steady state)			IIN	Under the operating conditions of the application circuit.	20	Arms
Load power			Wo	VAC=200V	4	kW
Chip junction temperature			Тј		150	°C
Operating case temperature		Тс	Center of the resin package on the reverse side *2	-20 to +105	°C	
Storage temperature		Tstg		-40 to +125	°C	
Tightening torque				M4 screws *3	1.17	N • m
Dielectric streng	gth voltage		VINS	Sine wave, 50Hz, AC 1 minute *4	2000	VRMS

*1. Repetitive peak current with the duty ratio of D=0.1 and tp=1ms.

*2. The measurement point must be within 10 millimeters square wide in the center of the resin package on the reverse side.

*3. The tightening torque must be within the range of 0.79 to 1.17N • m.

The flatness of the heat sink to be connected must be 0.15mm or less.

*4. Test conditions: AC 2500V for 1 second.

Electrical Characteristics at Tc=25°C, Vs=21V with the designated circuit

Parameter	Symbol	Conditions	min	typ	max	unit	Test circuit
Power output block	Power output block						
Collector-to-emitter cutoff current (TR2+TR3)	ICES	V _{CE} =600V			200	μA	Fig.1
Collector-to-emitter saturation voltage (TR2+TR3)	V _{CE} (sat)	V _{CC} =18.0V, I _C =40A		1.9	2.4	V	Fig.2
Diode reverse voltage (D2)	IR	V _R =600V			100	μA	Fig.1
Diode forward voltage (D2)	٧ _F	I _F =40A		2.1	2.6	V	Fig.3
Diode forward voltage (D3)	٧ _F	I _F =5A		2.5	3.5	V	Fig.3
Junction-to-case thermal resistance	θj-с1	IGBT (TR2+TR3)		0.75		°C /W	
	θj-c2	FRD (D2)		1.7		°C /W	
	өј-сЗ	FRD (D3)		9.0		°C /W	

(Apply V_{CC}=18.0V directly to pin 2 unless Vs input is specified.)

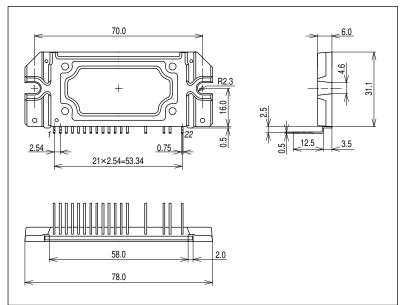
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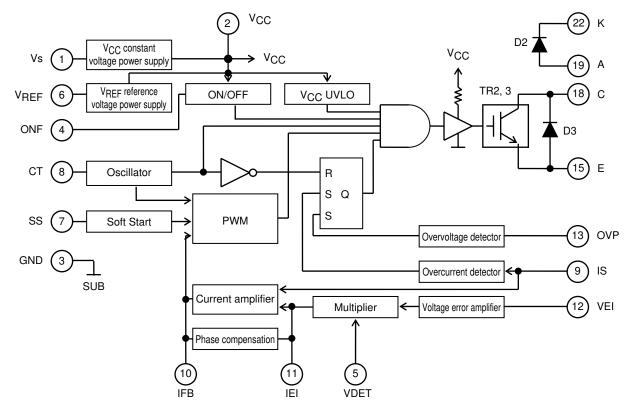
STK760-220A-E

Parameter	Symbol	Conditions	min	typ	max	unit	Test circuit	
V _{CC} regulator block								
V_{CC} regulator output voltage	VCC	Vs=21V, I _{CC} OUT=0 to 40mA	17.9	18.7	19.6	۷	Fig.4	
Control IC block								
Control circuit current dissipation	I _{CC} (ON)	V _{CC} =18.0V, ONF=5V		7	11	mA	Fig. F	
	I _{CC} (OFF)	V _{CC} =18.0V, ONF=0V		0.06	0.5	mA	Fig.5	
Reference voltage	V _{REF}	V _{CC} =18.0V, ONF=5V	4.75	5.0	5.25	V	F C	
Oscillation frequency	fosc	V _{CC} =18.0V, ONF=5V	21	25	28	kHz	Fig.5	
Overcurrent protection input threshold voltage	VTHOCP	V _{CC} =18.0V, ONF=5V	-1.20	-1.10	-1.00	V	Fig.6	
Voltage error amplifier reference voltage	Vr	V _{CC} =18.0V, ONF=5V	1.509	1.55	1.591	V	-	
OVP threshold voltage	VTHOVP	V _{CC} =18.0V, ONF=5V	1.607	1.64	1.673	V	F , 7	
SS charge current	ICHG	V _{CC} =18.0V, ONF=5V		11		μA	Fig.7	
SS input threshold voltage	VTHSS0	Duty cycle=0%		0.34		V		
	VTHSSM	Duty cycle=DMAX		3.4		V		
ON/OFF threshold voltage	VTHON	V _{CC} =18.0V	3.5	3.95	4.4	V	F . 0	
	VTHOFF	V _{CC} =18.0V	2.4	2.8	3.2	V	Fig.8	
Startup V _{CC} voltage	VTHUON	ONF=5V	15.5	16.5	17.5	V	Fig. 0	
Shutdown V _{CC} voltage	VTHUOFF	ONF=5V	8.2	8.9	9.6	V	Fig.9	
Power output block								
Switching time	ton	I _C =30A, Inductive load	0.2	0.35	0.8	μs		
	tOFF			0.85	1.4	μs	Eig 10	
	t _{rr}			0.04		μs	Fig.10	
Diode recovery current (D2)	۱ _{rr}			20		А		
Application circuit operation: Set to VAC=20	00V, and V _O =380	OV.						
Power factor	cosø	Wo=400W	0.9	0.95			Fig.11	
		Wo=2kW	0.98	0.99	1.0			

Package Dimensions unit:mm (typ)



Block Diagram



Pin Functions

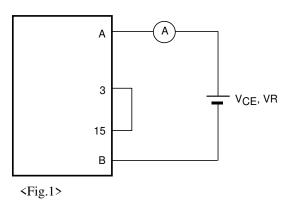
Pin No.	Pin Name	Description
1	Vs	Operating supply voltage (+18V Reg. input)
2	V _{CC}	+18V V _{CC} power supply output
3	GND	GND pin
4	ONF	ON/OFF control pin
5	VDET	Multiplication input
6	V _{REF}	+5V reference voltage output
7	SS	Soft start pin
8	СТ	Operating frequency setting pin
9	IS	Current detection signal
10	IFB	Phase compensation (current amplification output)
11	IEI	Current amplification input
12	VEI	Output voltage control input
13	OVP	Overvoltage limiting
14	-	No connection
15	E	TR2, 3 (IGBT) emitter
16, 17	-	No connection
18	С	TR2, 3 (IGBT) collector
19	А	D2 (FRD) anode
20, 21	-	No connection
22	К	D2 (FRD) cathode

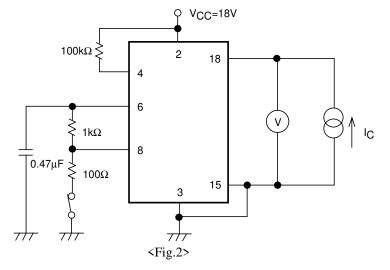
Test Circuit

1: IR, ICES

	TR1	D2
А	18	22
В	15	19

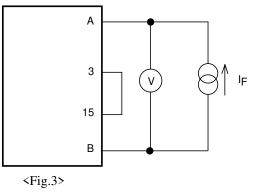
γ .	Vor(sat)	(Test	hv	nulce)
2.	V _{CE} (sat)	(1051	Uy	puise

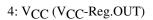


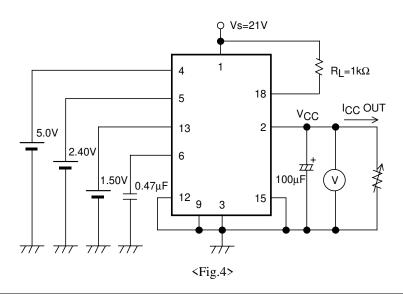


3: V_F (Test by pulse)

	D2	D3
А	19	15
В	22	18



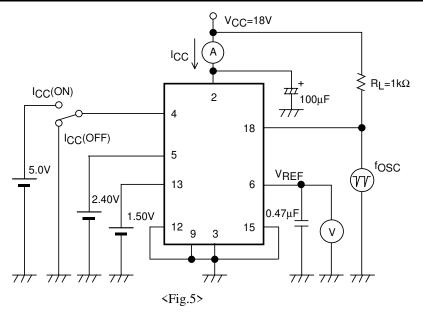




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5: ICC(ON)/ICC(OFF), VREF, fosc



6: Vr, VTHOCP

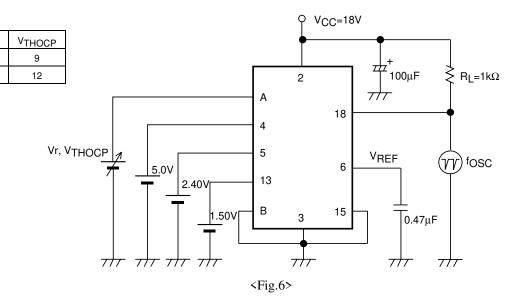
А

в

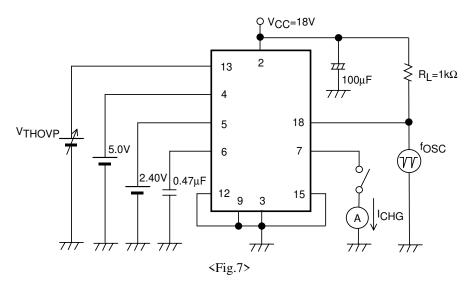
Vr

12

9



7: VTHOVP, ICHG

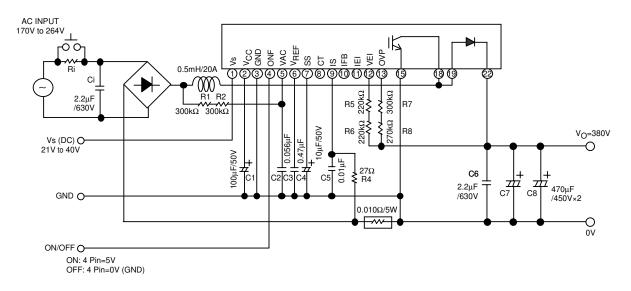


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8: VTHON, VTHOFF ♀ V_{CC}=18V 2 VREF 4 6 VONF 3 7/7 <Fig.8> 9: VTHUON, VTHUOFF 1 VCC 2 ON operation 7 VREF V_{CC} voltage 6 4 VREF V_{ONF}=5.0V Pin6 voltage Low 3 777 777 717 <Fig.9> 10: tON, tOFF, trr, Irr Input signal 22 2 (0 to 5V) Ø 100kΩ≯ VCC 4 V_{B} 19 100Ω t, Cs C 8 18 Irr (Input signal IC 90% Æ ΙC 0 3 15 10% tON tOFF <Fig.10> 11: Power factor (COS\$) AC INPUT 200V ١Ŀ Condition: VAC=200V V_O=380V w 0.5mH/20A (8) (9 65 Load1=400W Load2=2kW 70kΩ 300kΩ 2.2µF 220kD /630V 220kΩ 270kΩ Vs (DC) =21V O-٧_O 0.056µF 11 0.47µF 10µF/50V w 100µF/50V 0.01µF ₽ ş 27Ω 2.2μF /630V 470μF /450V×2 GND O-0.010Ω/5W O_{0V} ON/OFF O-ON: 4 Pin=5V OFF: 4 Pin=0V (GND) <Fig.11>

LOAD

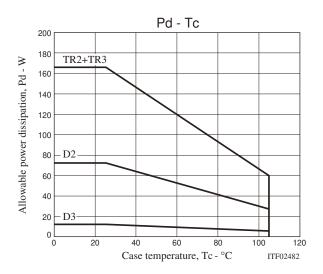
Sample Application Circuit



* When using the IC in a system having an input power voltage of 200V, insert a rush current limiting circuit, which consists of a limiting resistor Ri and a switch, to prevent the internal diodes from being damaged by the charging current from the output capacitor

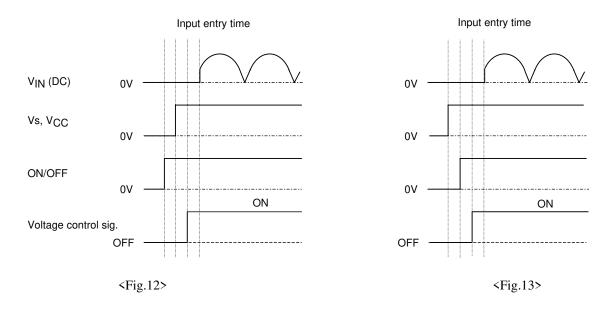
Recommended conditions

Parameter	Symbol	Conditions	Recommended values	unit
Commercial AC voltage	VAC	50/60Hz	170 to 264	Vrms
Output voltage	VO		VAC×√2+(10 to 15)≤ 450	V
Output overvoltage detection voltage	VOV		V _{OUT} +(10 to 20)	V
Supply voltage (Pin 1)	Vs		21 to 40	V



Timing Charts

The IC will never be subjected to fatal damage when a power supply input or signals are applied or are not applied at any timing. If the V_{IN} (DC) input is applied to the IC at the timing shown in Figure 12 or 13, however, since the soft start circuit is inactive in this case, it is likely that the overcurrent protection circuit is activated and audible tone is generated out of the coil. To avoid this area of timing, it is necessary that the ON/OFF or V_{CC} input be applied after V_{IN} (DC).



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